

Direct Z-scheme Heterojunction of CsPbBr₃/SnS₂ Nanosheets for Visible Light-Driven Photocatalytic CO₂ Reduction

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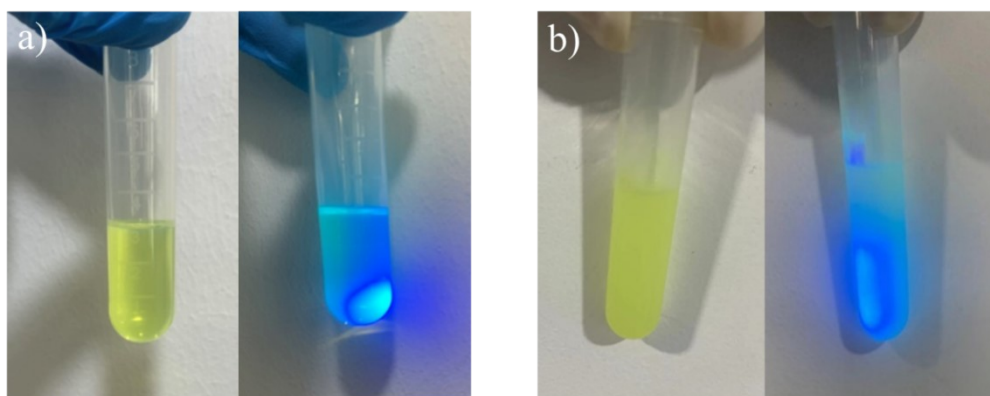


Figure S1 The photographic images of a) $\text{CsPbBr}_3\text{-OA}$ nanosheets and b) CsPbBr_3 nanosheets dispersed in hexane under room light (left) and excitation using an ultraviolet lamp under room temperature (right).

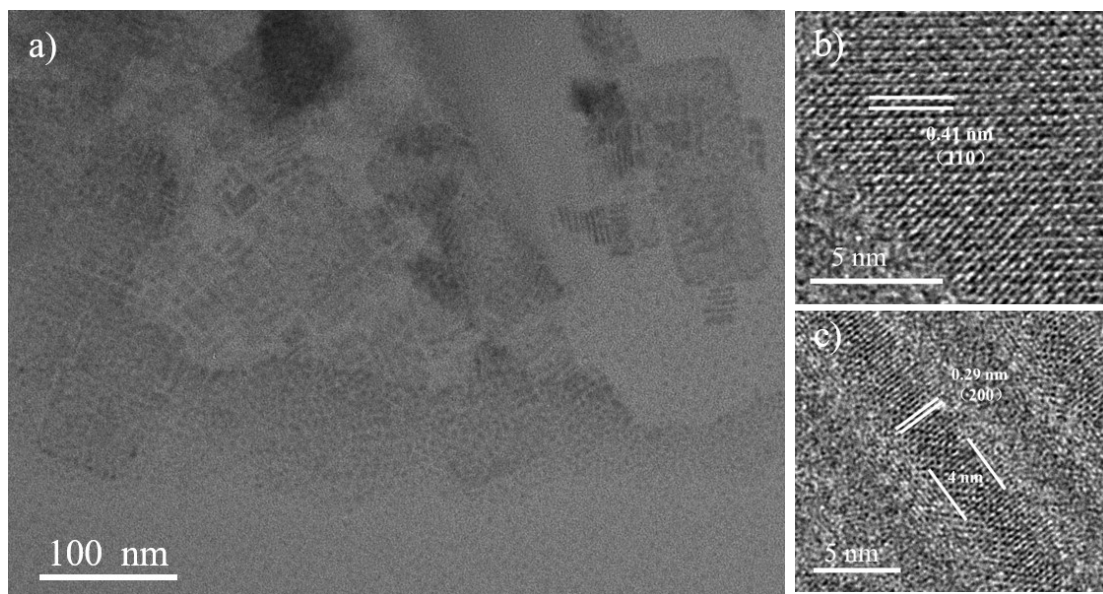


Figure S2 a) TEM image of CsPbBr₃-OA nanosheets. b-c) HRTEM images and lattice spacing of CsPbBr₃-OA nanosheets.

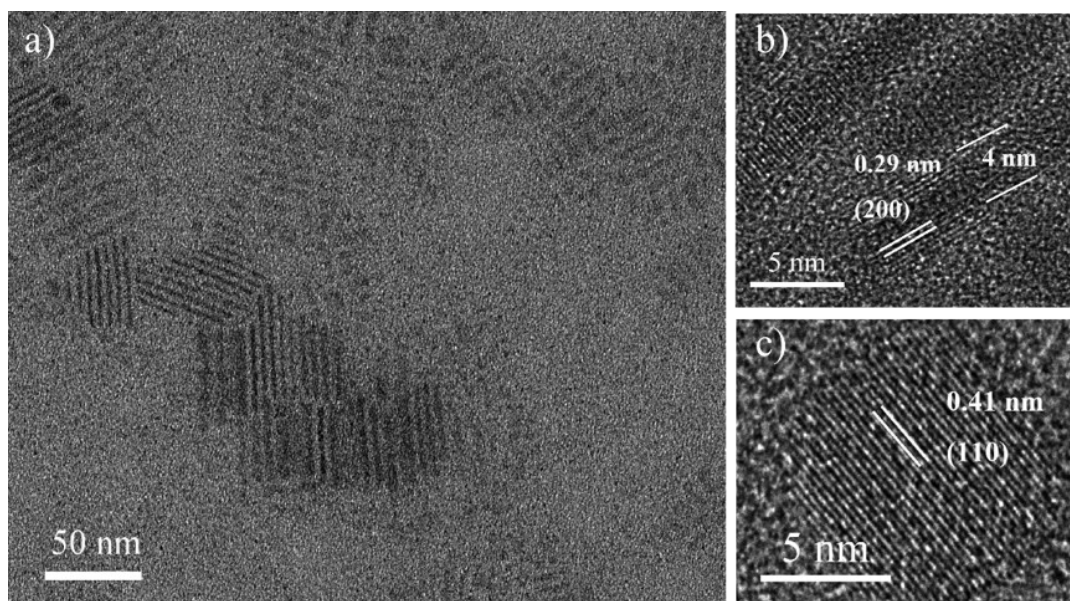


Figure S3 a) TEM image of CsPbBr_3 nanosheets. b-c) HRTEM images and lattice spacing of CsPbBr_3 nanosheets.

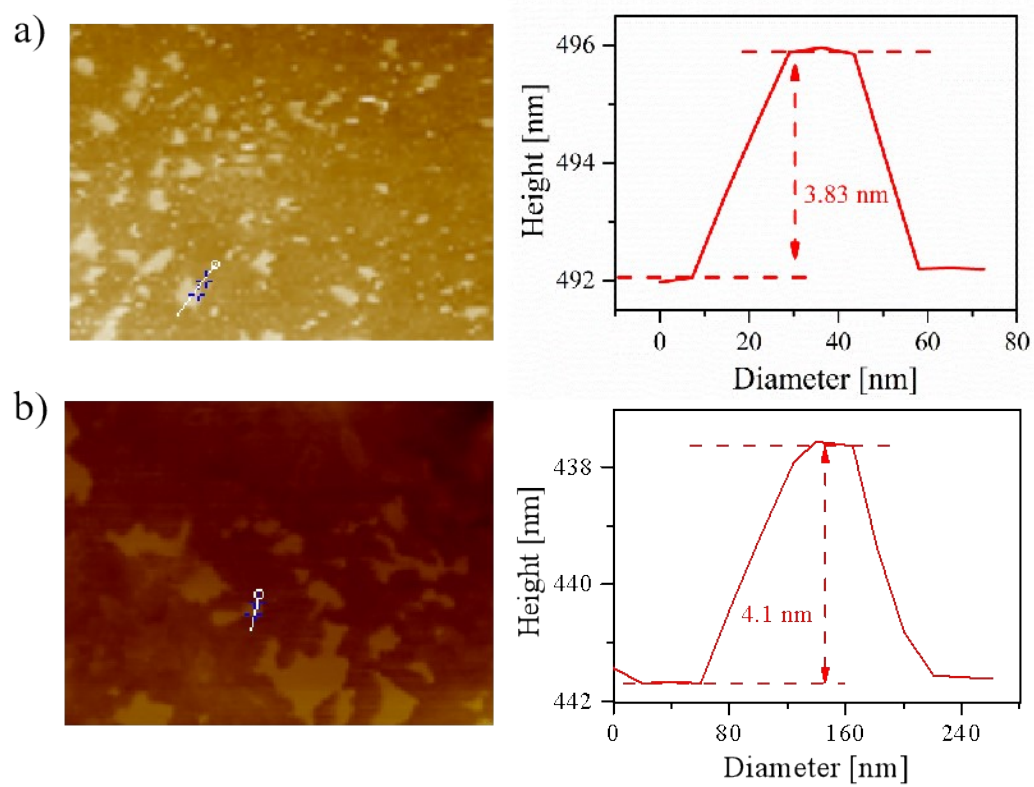


Figure S4 AFM images and corresponding height profiles of as prepared (a) CsPbBr₃ - OA nanosheets and (b) CsPbBr₃ nanosheets.

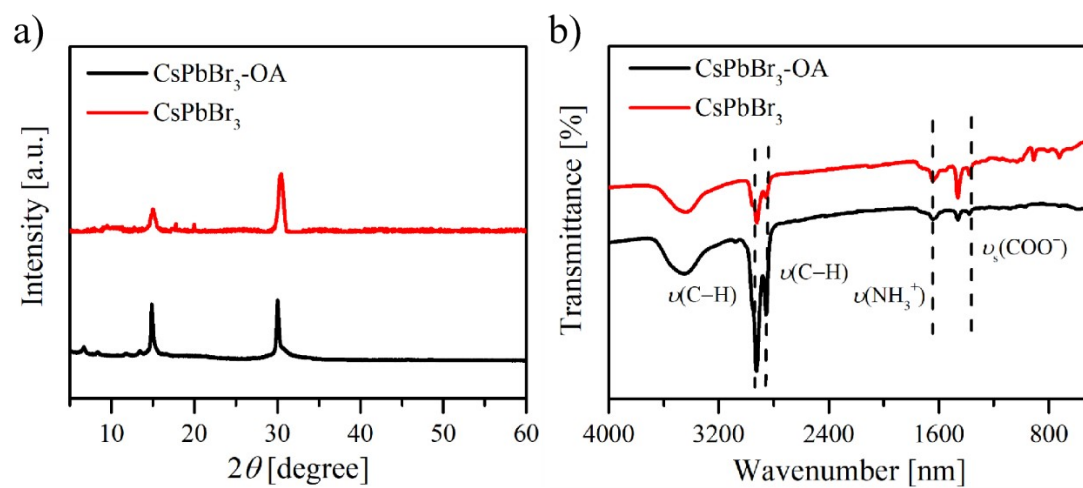


Figure S5 a) XRD patterns of CsPbBr₃-OA nanosheets and CsPbBr₃ nanosheets. b) IR spectrum of CsPbBr₃-OA nanosheets and CsPbBr₃ nanosheets.

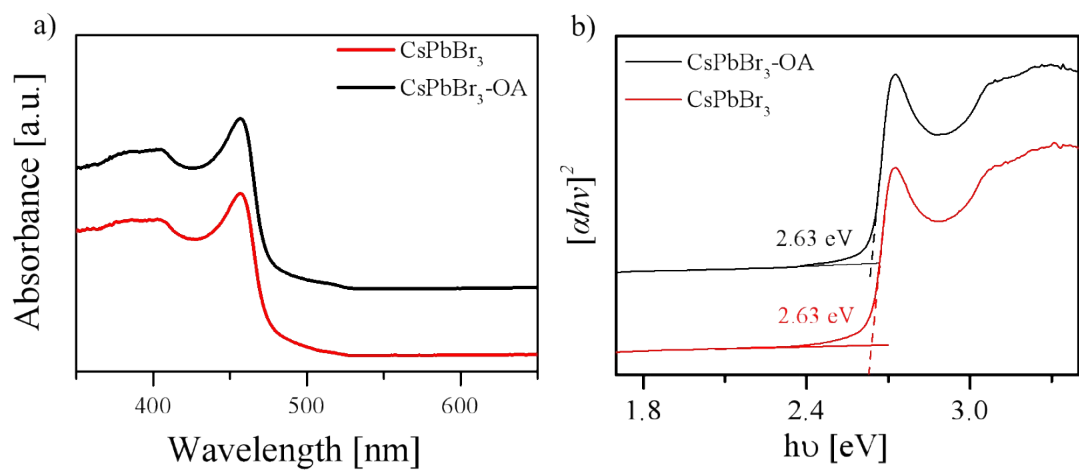


Figure S6 a) The UV-Vis absorption spectra of CsPbBr₃-OA nanosheets and CsPbBr₃ nanosheets. b) The Tauc plots of CsPbBr₃-OA nanosheets and CsPbBr₃ nanosheets.

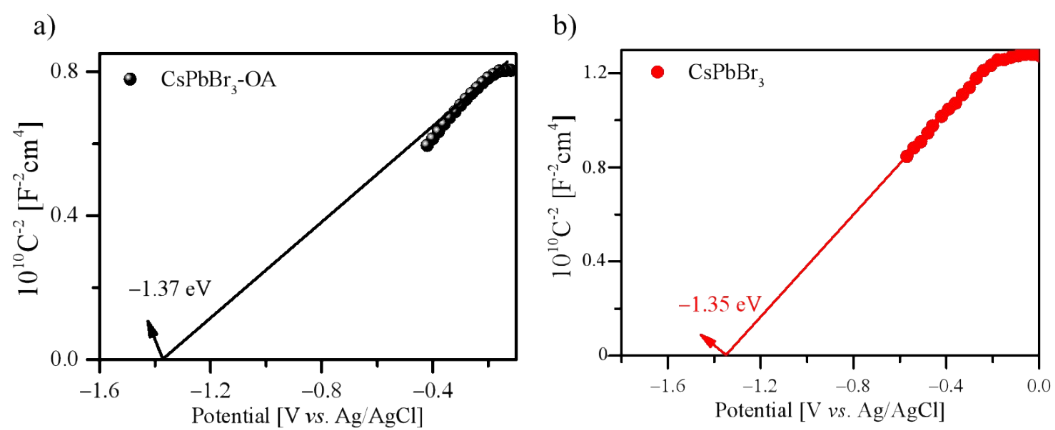


Figure S7 a) The UV-Vis absorption spectra of CsPbBr₃-OA nanosheets and CsPbBr₃ nanosheets. b) The Tanuc plots of CsPbBr₃-OA nanosheets and CsPbBr₃ nanosheets.

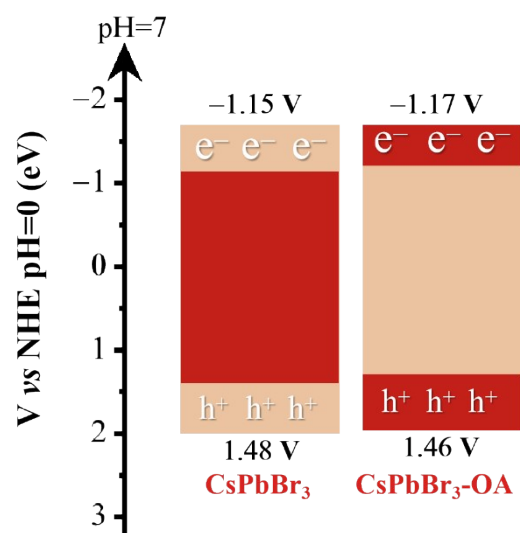


Figure S8 The band alignment of $\text{CsPbBr}_3\text{-OA}$ nanosheets and CsPbBr_3 nanosheets.

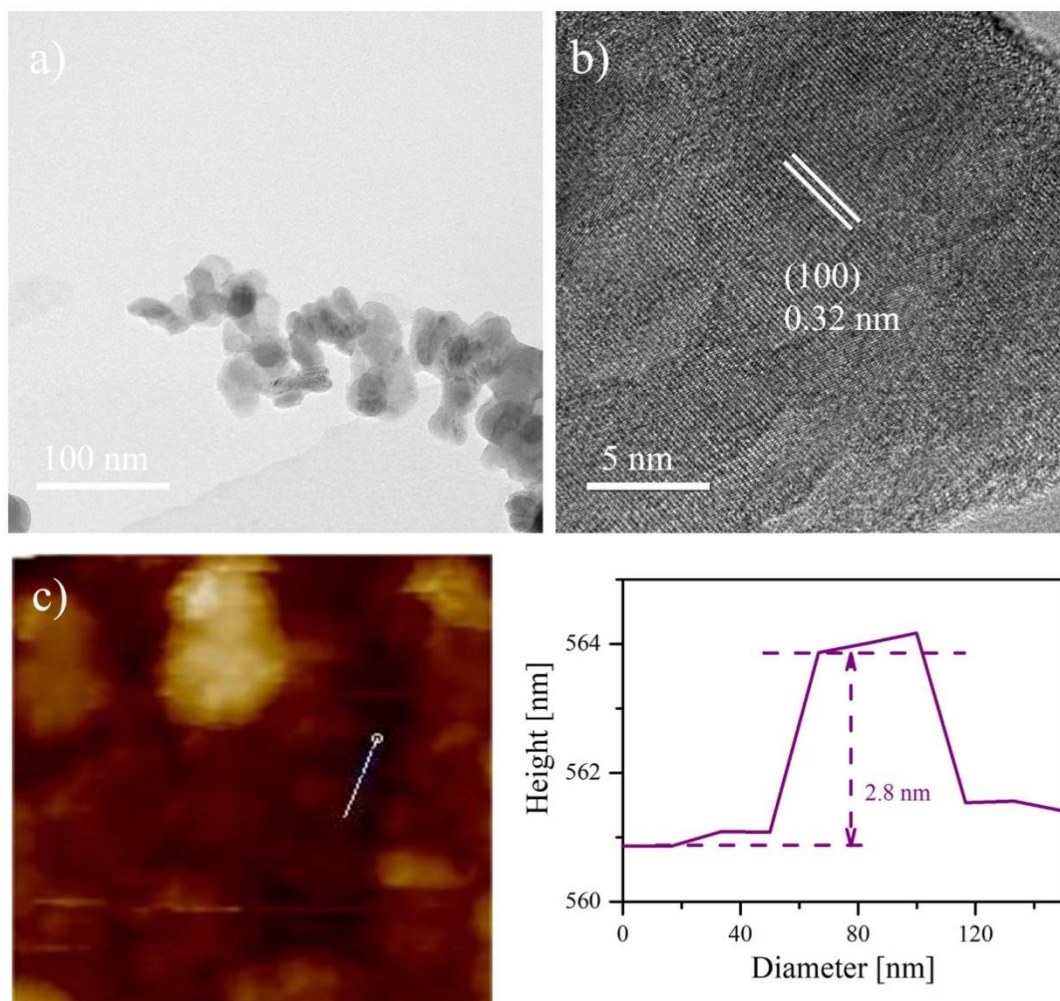


Figure S9 a) TEM, b) HRTEM images with lattice spacing of as prepared SnS₂ nanosheets. c) AFM image and corresponding height profiles of as prepared SnS₂ nanosheets.

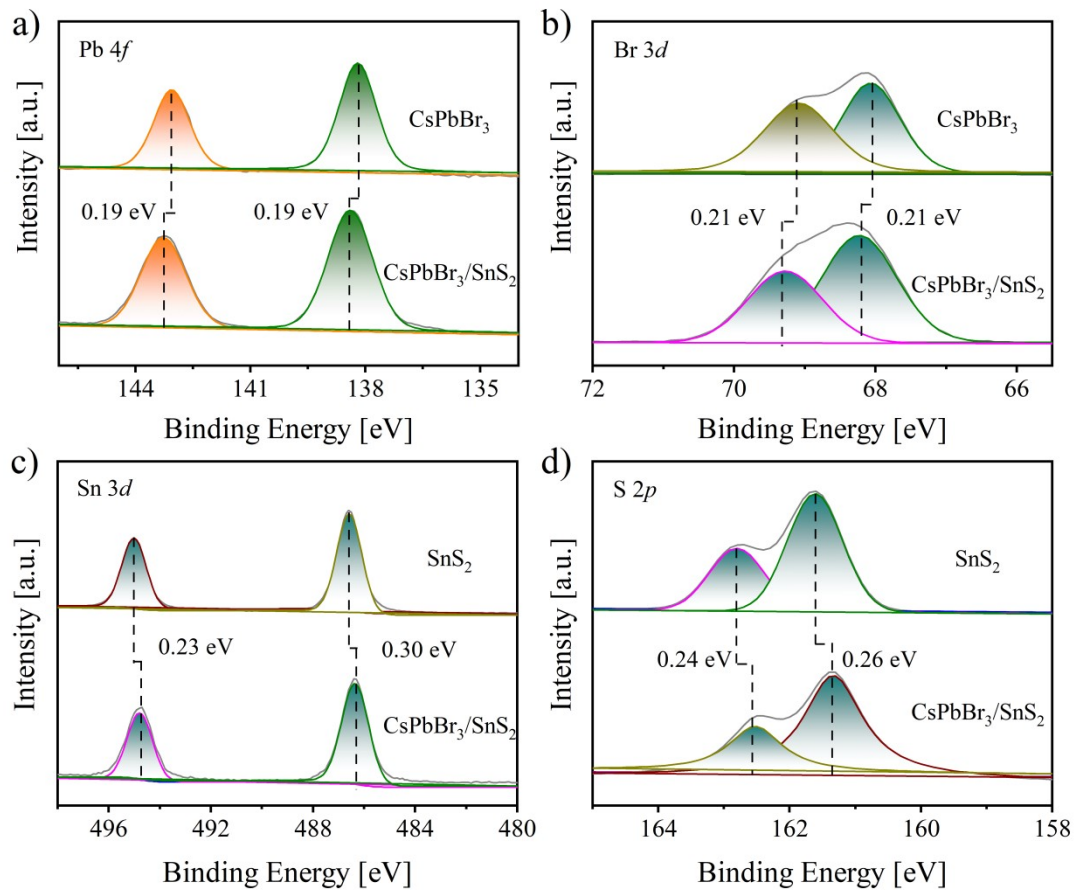


Figure S10 High-resolution XPS spectra of CsPbBr₃/SnS₂ composites in the dark (a) Pb 4f, (b) Br 3d, (c) Sn 3d and (d) S 2p.

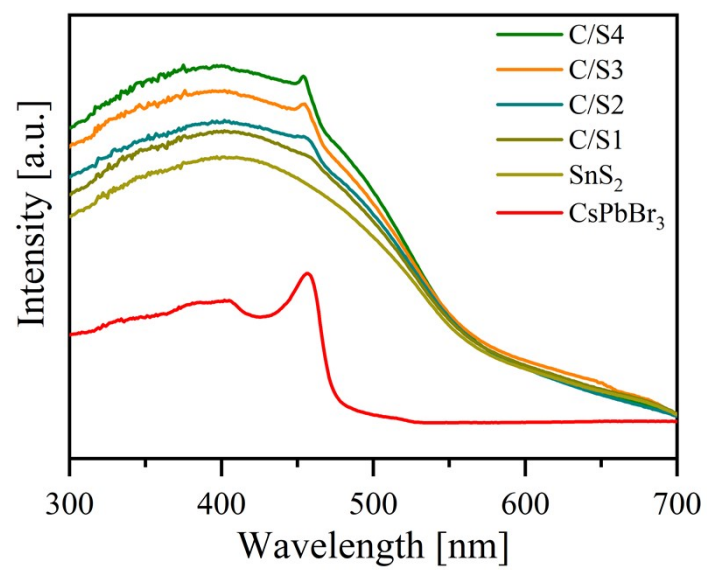


Figure S11 UV-Vis DRS spectra of S/Cx heterojunctions.

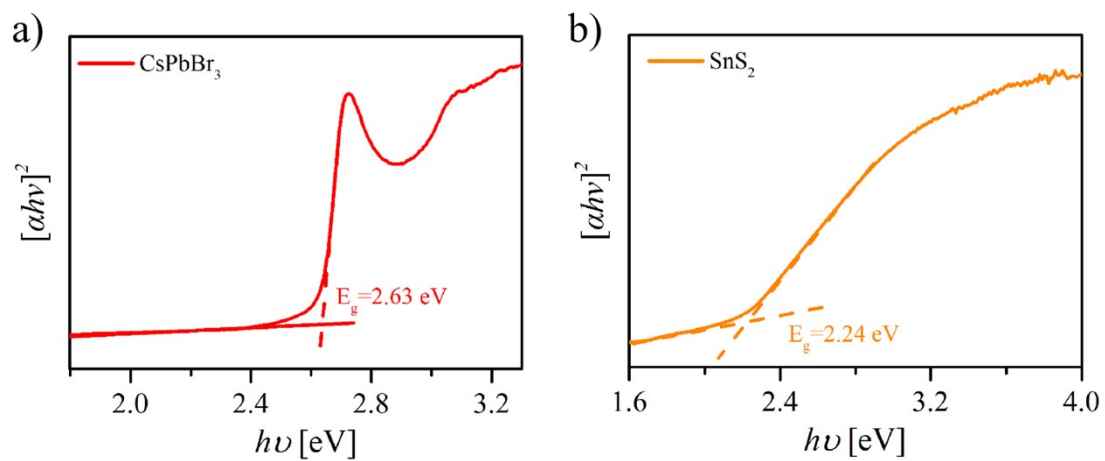


Figure S12 Tauc plots of CsPbBr₃ nanosheets and SnS₂ nanosheets.

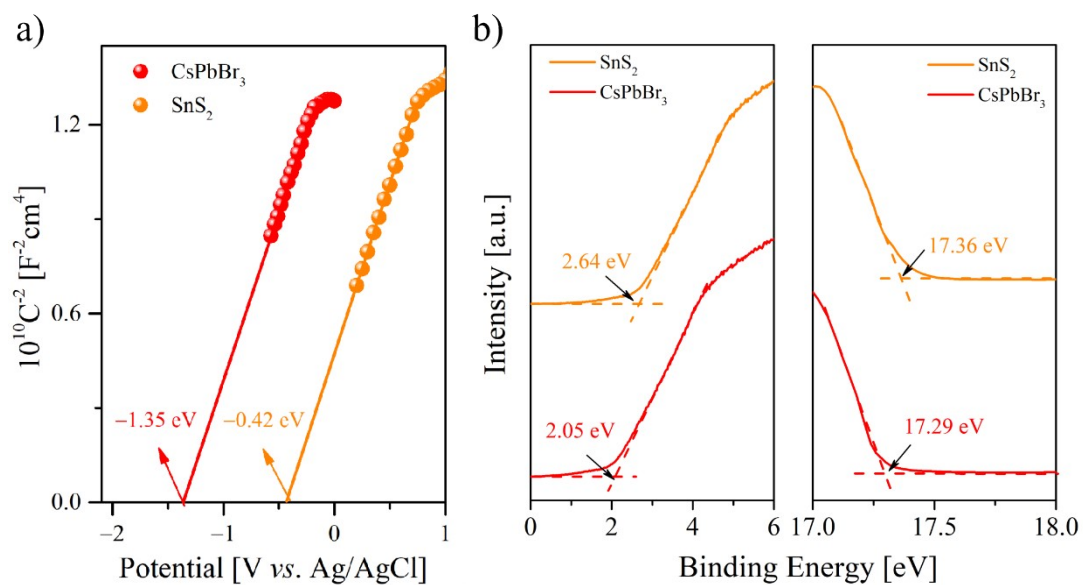


Figure S13 a) The Mott-Schottky plots and b) UPS spectras of SnS_2 nanosheets and $CsPbBr_3$ nanosheets.

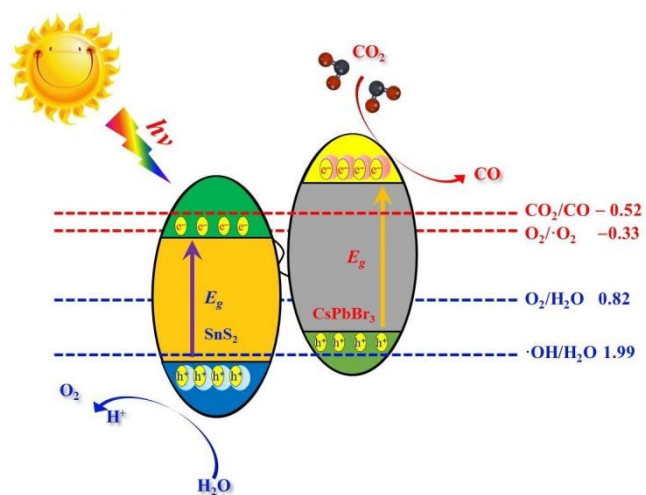


Figure S14 The band alignment of CsPbBr₃ nanosheets and SnS₂ nanosheets.

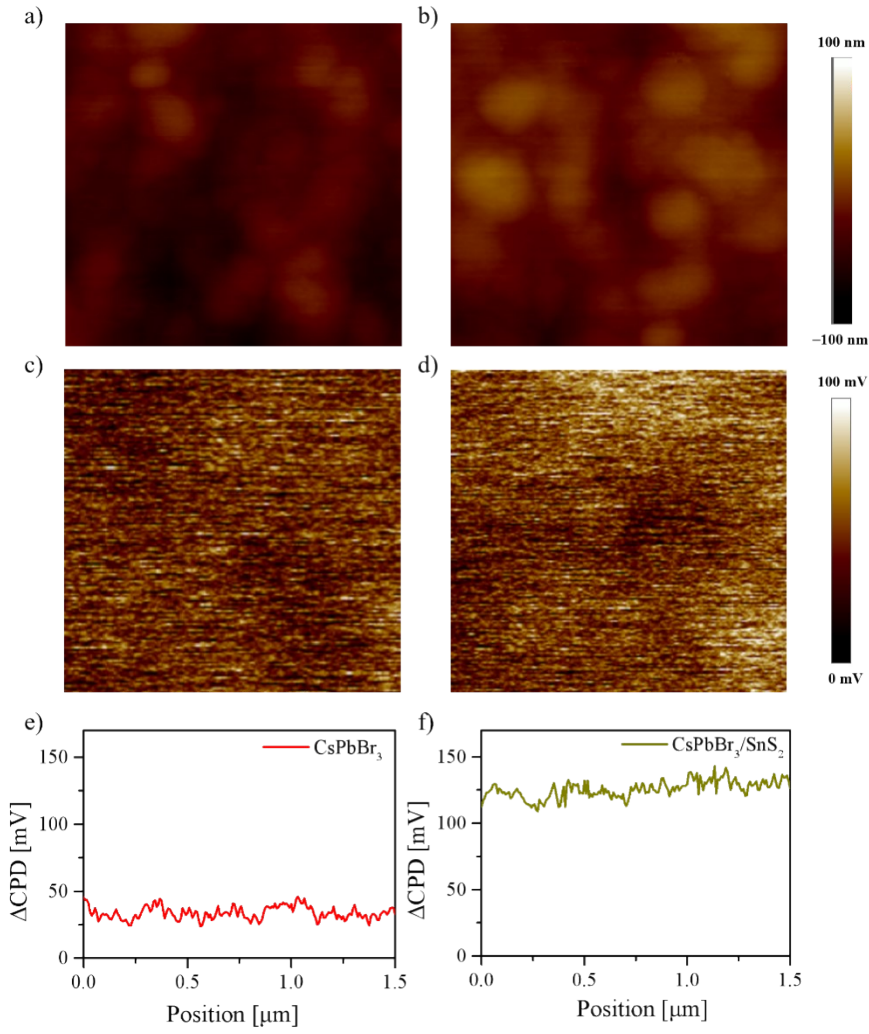


Figure S15 Height images of a) CsPbBr₃ and b) S/C2 heterojunctions. The differential surface photovoltage (SPV) images of c) CsPbBr₃ and d) S/C2 heterojunctions between potential images under illumination. Contact potential difference changes (ΔCPD) of e) CsPbBr₃ and f) S/C2 heterojunctions by subtracting the potential in the dark conditions from that under illumination.

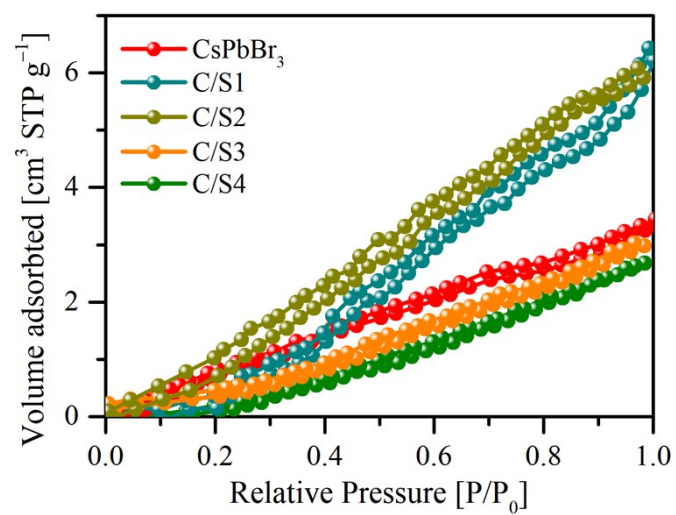
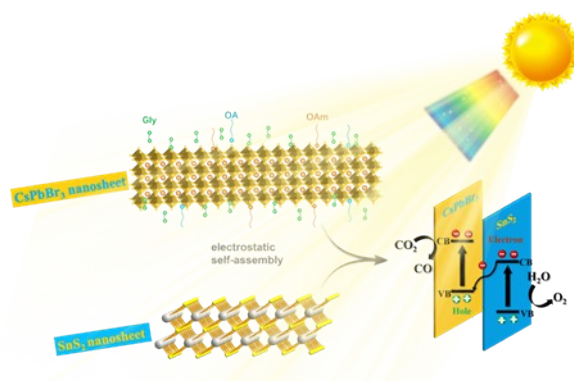


Figure S16 Carbon dioxide adsorption-desorption isotherm (BET) of CsPbBr₃/SnS₂ heterojunctions.

Table S1 Multi-exponential fitting parameters for the PL decays of CsPbBr₃/SnS₂ heterojunctions (Figure 3d). Excitation at 410 nm and detection at 460 nm.

Smamples	τ_1 [ns] (A ₁)	τ_2 [ns] (A ₂)	τ_3 [ns] (A ₃)	τ_{Ave} [ns]
CsPbBr ₃	0.77 (31.69%)	3.08 (46.16%)	9.56 (22.15%)	3.77
C/S1	0.48 (37.98%)	3.73 (37.51%)	25.38 (24.51%)	7.80
C/S2	1.91 (15.04%)	8.45 (42.54%)	36.43 (42.43%)	19.34
C/S3	0.79 (20.81%)	5.41 (41.64%)	32.88 (37.55%)	14.77
C/S4	1.11 (17.72%)	5.97 (47.75%)	28.11 (34.53%)	12.75



CsPbBr₃/SnS₂ Z-scheme heterojunctions were subtly constructed for visible-light-driven CO₂-to-CO conversion. This dual-nanosheet assembly is bonded via electrostatic attraction and exhibits excellent performance for CO₂ reduction to CO. The atomic-scale proximity in the 2D/2D architecture ensures efficient interfacial Z-scheme charge transfer.